

# Low Charge Injection 8-Channel Enhanced High Voltage Analog Switch

## Features

- ▶ HVCMOS technology for high performance
- ▶ 8 Channels of high voltage analog switch
- ▶ 3.3V or 5V CMOS input logic level
- ▶ 20MHz data shift clock frequency
- ▶ Very low quiescent power dissipation-10 $\mu$ A
- ▶ Low parasitic capacitance
- ▶ DC to 10MHz analog signal frequency
- ▶ -60dB typical off-isolation at 5MHz
- ▶ CMOS logic circuitry for low power
- ▶ Excellent noise immunity
- ▶ Cascadable serial data register with latches
- ▶ Flexible operating supply voltages

## Applications

- ▶ Medical ultrasound imaging
- ▶ NDT metal flaw detection
- ▶ Piezoelectric transducer drivers
- ▶ Inkjet printer heads
- ▶ Optical MEMS modules

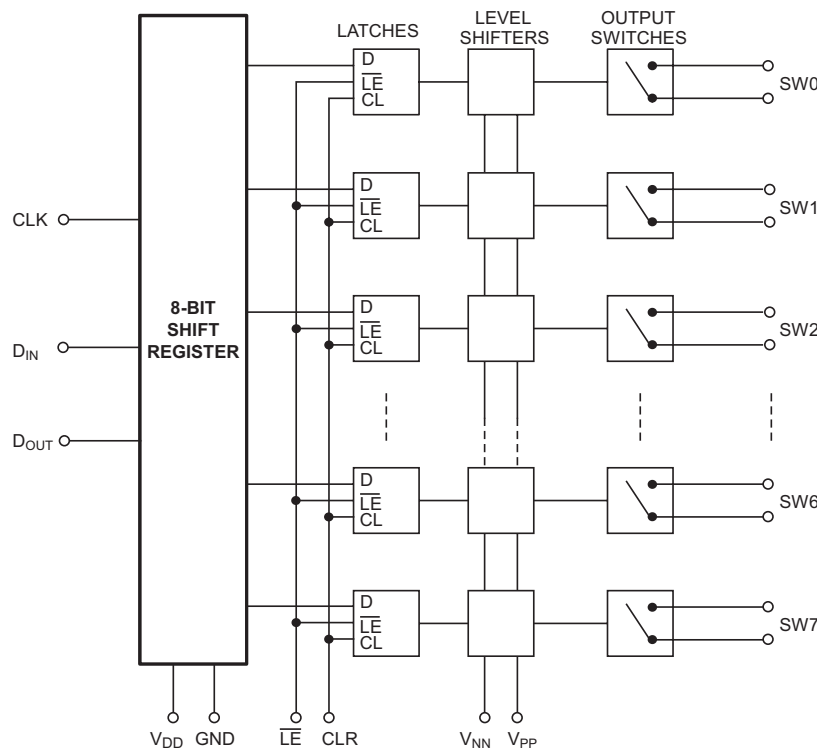
## General Description

The Supertex HV2201 is a low charge injection, 8-channel, high voltage analog switch integrated circuit (IC). The device can be used in applications requiring high voltage switching controlled by low voltage control signals, such as medical ultrasound imaging, piezoelectric transducer drivers, and printers. The HV2201 is an enhanced version of the HV20220.

Input data is shifted into an 8-bit shift register that can then be retained in an 8-bit latch. To reduce any possible clock feed-through noise, the latch enable bar should be left high until all bits are clocked in. Data is clocked in during the rising edge of the clock. Using HVCMOS technology, this device combines high voltage bilateral DMOS switches and low power CMOS logic to provide efficient control of high voltage analog signals.

The device is suitable for various combinations of high voltage supplies, e.g.,  $V_{PP}/V_{NN}$ : +40V/-160V, +100V/-100V, and +160V/-40V.

## Block Diagram



**Ordering Information**

Device	Package Options		
	48-Lead TQFP	28-Lead PLCC	32-Lead BCC
HV2201	HV2201FG-G	HV2201PJ-G	HV2201B1-G



-G indicates package is RoHS compliant ("Green")

**Absolute Maximum Ratings**

Parameter	Value
V <sub>DD</sub> logic supply	-0.5V to +7V
V <sub>PP</sub> -V <sub>NN</sub> differential supply	220V
V <sub>PP</sub> positive supply	-0.5V to V <sub>NN</sub> +200V
V <sub>NN</sub> negative supply	+0.5V to -200V
Logic input voltage	-0.5V to V <sub>DD</sub> +0.3V
Analog signal range	V <sub>NN</sub> to V <sub>PP</sub>
Peak analog signal current/channel	3.0A
Storage temperature	-65°C to 150°C
Power dissipation:	
48-Lead TQFP	1.0W
28-Lead PLCC	1.2W
32-Lead BCC	1.0W

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

**Operating Conditions**

Symbol	Parameter	Value
V <sub>DD</sub>	Logic power supply voltage	3.0V to 5.5V
V <sub>PP</sub>	positive high voltage supply	40V to V <sub>NN</sub> +200V
V <sub>NN</sub>	negative high voltage supply	-40V to -160V
V <sub>IH</sub>	High level input voltage	0.9V to V <sub>DD</sub>
V <sub>IL</sub>	Low-level input voltage	0V to 0.1V
V <sub>SIG</sub>	Analog signal voltage peak-to-peak	V <sub>NN</sub> +10V to V <sub>PP</sub> -10V
T <sub>A</sub>	Operating free air temperature	0°C to 70°C

Notes:

1. Power up/down sequence is arbitrary except GND must be powered -up first and powered down last.
2. V<sub>SIG</sub> must be V<sub>NN</sub> ≤ V<sub>SIG</sub> ≤ V<sub>PP</sub> or floating during power up/down transition.
3. Rise and fall times of power supplies V<sub>DD</sub>, V<sub>PP</sub> and V<sub>NN</sub> should not be less than 1.0msec.

## DC Electrical Characteristics

(Over operating conditions unless otherwise specified )

Sym	Parameter	0°C		+25°C			+70°C		Units	Conditions	
		Min	Max	Min	Typ	Max	Min	Max			
R <sub>ONS</sub>	Small signal switch on-resistance	-	30	-	26	38	-	48	Ω	I <sub>SIG</sub> = 5mA	V <sub>PP</sub> = +40V V <sub>NN</sub> = -160V
		-	25	-	22	27	-	32		I <sub>SIG</sub> = 200mA	V <sub>NN</sub> = -160V
		-	25	-	22	27	-	30		I <sub>SIG</sub> = 5mA	V <sub>PP</sub> = +100V V <sub>NN</sub> = -100V
		-	18	-	18	24	-	27		I <sub>SIG</sub> = 200mA	V <sub>NN</sub> = -100V
		-	23	-	20	25	-	30		I <sub>SIG</sub> = 5mA	V <sub>PP</sub> = +160V V <sub>NN</sub> = -40V
		-	22	-	16	25	-	27		I <sub>SIG</sub> = 200mA	V <sub>NN</sub> = -40V
ΔR <sub>ONS</sub>	Small signal switch on-resistance matching	-	20	-	5.0	20	-	20	%	I <sub>SIG</sub> = 5mA, V <sub>PP</sub> = +100V, V <sub>NN</sub> = -100V	
R <sub>ONL</sub>	Large signal switch on-resistance	-	-	-	15	-	-	-	Ω	V <sub>SIG</sub> = V <sub>PP</sub> -10V, I <sub>SIG</sub> = 1A	
I <sub>SOL</sub>	Switch off leakage per switch	-	5.0	-	1.0	10	-	15	μA	V <sub>SIG</sub> = V <sub>PP</sub> -10V, V <sub>NN</sub> +10V	
V <sub>OS</sub>	DC offset switch off	-	300	-	100	300	-	300	mV	100kΩ load	
	DC offset switch on	-	500	-	100	500	-	500	mV		
I <sub>PPQ</sub>	Quiescent V <sub>PP</sub> supply current	-	-	-	10	50	-	-	μA	All switches off	
I <sub>NNQ</sub>	Quiescent V <sub>NN</sub> supply current	-	-	-	-10	-50	-	-	μA	All switches off	
I <sub>PPQ</sub>	Quiescent V <sub>PP</sub> supply current	-	-	-	10	50	-	-	μA	All switches on, I <sub>SW</sub> = 5mA	
I <sub>NNQ</sub>	Quiescent V <sub>NN</sub> supply current	-	-	-	-10	-50	-	-	μA	All switches on, I <sub>SW</sub> = 5mA	
I <sub>SW</sub>	Switch output peak current	-	3.0	-	3.0	2.0	-	2.0	A	V <sub>SIG</sub> duty cyclcy < 0.1%	
f <sub>SW</sub>	Output switching frequency	-	-	-	-	50	-	-	kHz	Duty cycle = 50%	
I <sub>PP</sub>	Average V <sub>PP</sub> supply current	-	4.0	-	-	5.0	-	5.5	mA	V <sub>PP</sub> = +40V V <sub>NN</sub> = -160V	All output switches are turning On and Off at 50kHz with no load
		-	3.5	-	-	3.5	-	3.5		V <sub>PP</sub> = +100V V <sub>NN</sub> = -100V	
		-	3.5	-	-	3.5	-	4.0		V <sub>PP</sub> = +160V V <sub>NN</sub> = -40V	
I <sub>NN</sub>	Average V <sub>NN</sub> supply curent	-	4.5	-	-	5.0	-	5.5	mA	V <sub>PP</sub> = +40V V <sub>NN</sub> = -160V	
		-	3.5	-	-	3.5	-	3.5		V <sub>PP</sub> = +100V V <sub>NN</sub> = -100V	
		-	3.5	-	-	3.5	-	4.0		V <sub>PP</sub> = +160V V <sub>NN</sub> = -40V	
I <sub>DD</sub>	Average V <sub>DD</sub> supply current	-	4.0	-	-	4.0	-	4.0	mA	f <sub>CLK</sub> = 5MHz, V <sub>DD</sub> = 5.0V	
I <sub>DDQ</sub>	Quiescent V <sub>DD</sub> supply current	-	10	-	-	10	-	10	μA	All logic inputs are static	
I <sub>SOR</sub>	Data out source current	0.45	-	0.45	0.70	-	0.40	-	mA	V <sub>OUT</sub> = V <sub>DD</sub> -0.7V	
I <sub>SINK</sub>	Data out sink current	0.45	-	0.45	0.70	-	0.40	-	mA	V <sub>OUT</sub> = 0.7V	
C <sub>IN</sub>	Logic input capacitance	-	10	-	-	10	-	10	pF	---	

## AC Electrical Characteristics

(Over recommended operating conditions:  $V_{DD} = 5.0V$ ,  $t_R = t_F \leq 5ns$ , 50% duty cycle,  $C_{LOAD} = 20pF$ , unless otherwise specified)

Sym	Parameter	0°C		+25°C			+70°C		Units	Conditions
		Min	Max	Min	Typ	Max	Min	Max		
$t_{SD}$	Set up time before $\overline{LE}$ rises	25	-	25	-	-	25	-	ns	---
$t_{WLE}$	Time width of $\overline{LE}$	56	-	-	56	-	56	-	ns	$V_{DD} = 3.0V$
		12	-	-	12	-	12	-		$V_{DD} = 5.0V$
$t_{DO}$	Clock delay time to data out	-	120	-	95	140	-	167	ns	$V_{DD} = 3.0V$
		-	58	-	40	69	-	85		$V_{DD} = 5.0V$
$t_{WCL}$	Time width of CL	55	-	55	-	-	55	-	ns	---
$t_{SU}$	Set up time data to clock	39	-	47	30	-	58	-	ns	$V_{DD} = 3.0V$
		16	-	21	10	-	26	-		$V_{DD} = 5.0V$
$t_H$	Hold time data from clock	2	-	2	-	-	2	-	ns	$V_{DD} = 3.0$ or $5.0V$
$f_{CLK}$	Clock frequency	-	-	-	8	-	-	-	MHz	$V_{DD} = 3.0V$
		-	-	-	20	-	-	-		$V_{DD} = 5.0V$
$t_R, t_F$	Clock rise and fall times	-	50	-	-	50	-	50	ns	---
$t_{ON}$	Turn on time	-	5.0	-	-	5.0	-	5.0	$\mu s$	$V_{SIG} = V_{PP} - 10V, R_{LOAD} = 10k\Omega$
$t_{OFF}$	Turn off time	-	5.0	-	-	5.0	-	5.0	$\mu s$	$V_{SIG} = V_{PP} - 10V, R_{LOAD} = 10k\Omega$
dv/dt	Maximum $V_{SIG}$ slew rate	-	20	-	-	20	-	20	V/ns	$V_{PP} = +40V, V_{NN} = -160V$
		-	20	-	-	20	-	20		$V_{PP} = +100V, V_{NN} = -100V$
		-	20	-	-	20	-	20		$V_{PP} = +160V, V_{NN} = -40V$
$K_O$	Off isolation	-30	-	-30	-33	-	-30	-	dB	$f = 5.0MHz, 1k\Omega/15pF$ load
		-58	-	-58	-	-	-58	-		$f = 5.0MHz, 50\Omega$ load
$K_{CR}$	Switch crosstalk	-60	-	-60	-70	-	-60	-	dB	$f = 5.0MHz, 50\Omega$ load
$I_{ID}$	Output switch isolation diode current	-	300	-	-	300	-	300	mA	300ns pulse width, 2.0% duty cycle
$C_{SG(OFF)}$	Off capacitance SW to GND	5.0	17	5.0	12	17	5.0	17	pF	0V, $f = 1.0MHz$
$C_{SG(ON)}$	On capacitance SW to GND	25	50	25	38	50	25	50	pF	0V, $f = 1.0MHz$
$+V_{SPK}$	Output voltage spike	-	-	-	-	150	-	-	mV	$V_{PP} = +40V, V_{NN} = -160V, R_{LOAD} = 50\Omega$
$-V_{SPK}$		-	-	-	-	150	-	-		$V_{PP} = +100V, V_{NN} = -100V, R_{LOAD} = 50\Omega$
$+V_{SPK}$		-	-	-	-	150	-	-		$V_{PP} = +160V, V_{NN} = -40V, R_{LOAD} = 50\Omega$
$-V_{SPK}$		-	-	-	-	150	-	-		
$+V_{SPK}$		-	-	-	-	150	-	-		
$-V_{SPK}$		-	-	-	-	150	-	-		
QC	Charge injection	-	-	-	820	-	-	-	pC	$V_{PP} = +40V, V_{NN} = -160V, V_{SIG} = 0V$
		-	-	-	600	-	-	-		$V_{PP} = +100V, V_{NN} = -100V, V_{SIG} = 0V$
		-	-	-	350	-	-	-		$V_{PP} = +160V, V_{NN} = -40V, V_{SIG} = 0V$

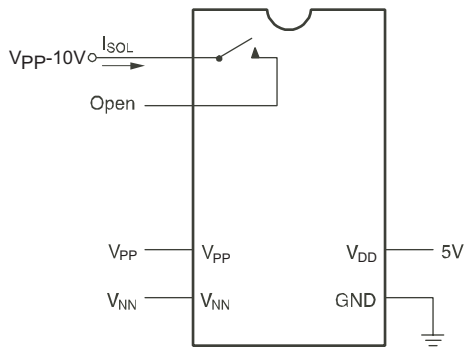
## Truth Table

D0	D1	D2	D3	D4	D5	D6	D7	LE	CLR	SW0	SW1	SW2	SW3	SW4	SW5	SW6	SW7
L								L	L	Off							
H								L	L	On							
	L							L	L		Off						
	H							L	L		On						
		L						L	L			Off					
		H						L	L			On					
			L					L	L				Off				
			H					L	L				On				
				L				L	L					Off			
				H				L	L					On			
					L			L	L						Off		
					H			L	L						On		
						L		L	L							Off	
						H		L	L							On	
							L	L	L								Off
							H	L	L								On
X	X	X	X	X	X	X	X	H	L	Hold Previous State							
X	X	X	X	X	X	X	X	X	H	All Switches Off							

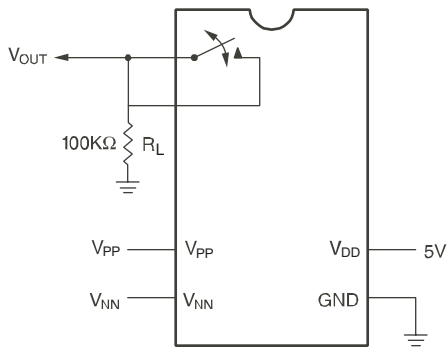
## Notes:

1. The eight switches operate independently.
2. Serial data is clocked in on the L to H transition of the CLK.
3. The switches go to a state retaining their present condition at the rising edge of LE. When LE is low the shift register data flow through the latch.
4.  $D_{OUT}$  is high when data in the register 7 is high.
5. Shift register clocking has no effect on the switch states if LE is high.
6. The CLR clear input overrides all other inputs.

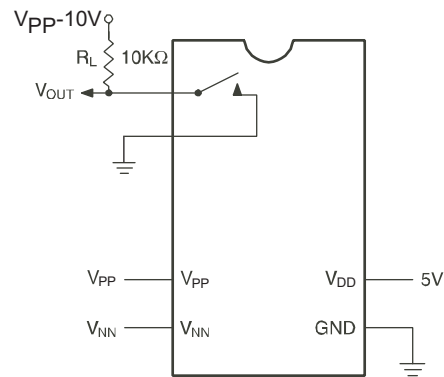
Test Circuits



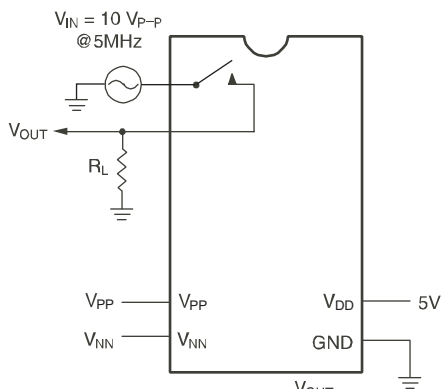
Switch OFF Leakage



DC Offset ON/OFF

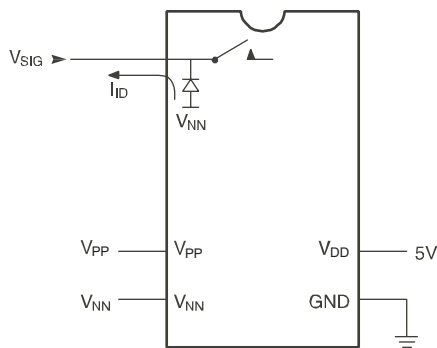


T<sub>ON</sub>/T<sub>OFF</sub> Test Circuit

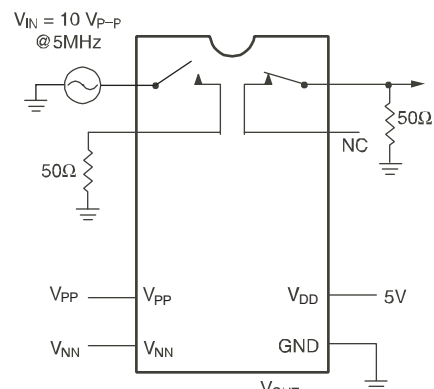


$$K_O = 20 \text{Log} \frac{V_{OUT}}{V_{IN}}$$

OFF Isolation

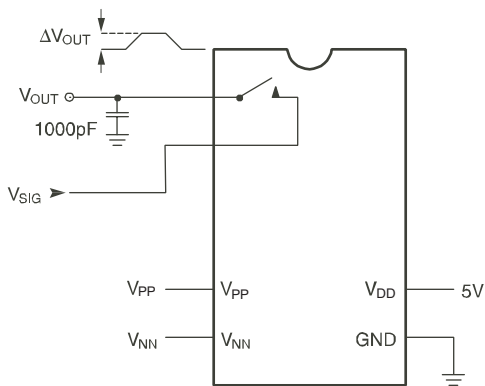


Isolation Diode Current



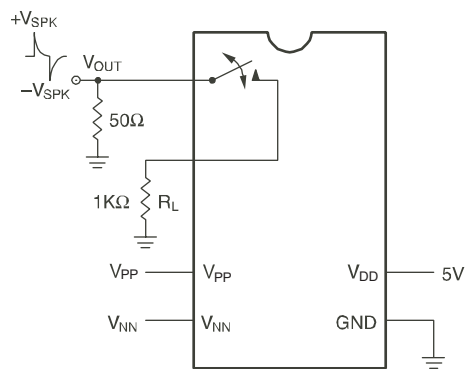
$$K_{CR} = 20 \text{Log} \frac{V_{OUT}}{V_{IN}}$$

Crosstalk



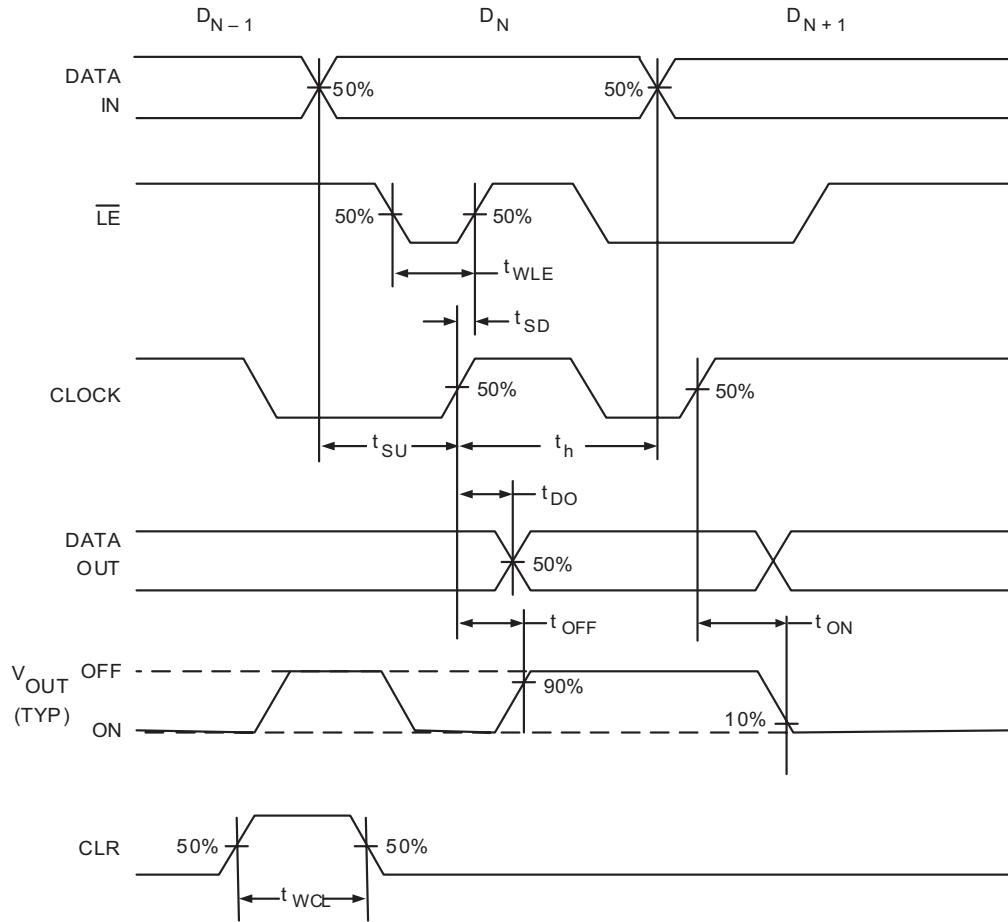
$$Q = 1000\text{pF} \times \Delta V_{OUT}$$

Charge Injection

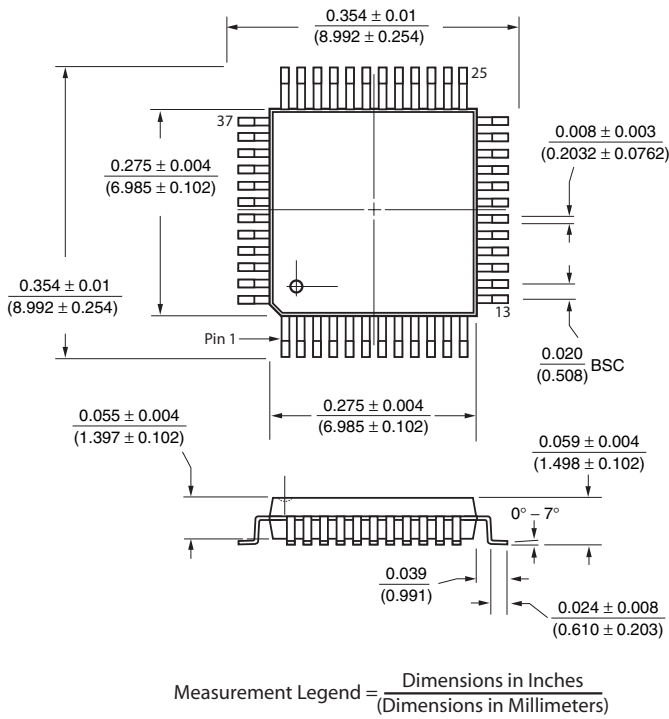


Output Voltage Spike

Typical Waveforms



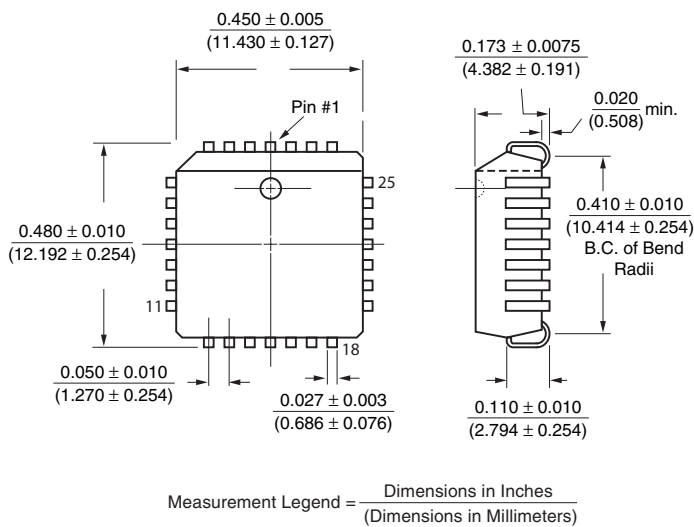
**48-Lead TQFP (1.4mm)  
Package Outline (FG)**



**Pin Configuration**

Pin #	Pin Name	Pin #	Pin Name
1	SW5	25	V <sub>NN</sub>
2	NC	26	NC
3	SW4	27	NC
4	NC	28	GND
5	SW4	29	V <sub>DD</sub>
6	NC	30	NC
7	NC	31	NC
8	SW3	32	NC
9	NC	33	D <sub>IN</sub>
10	SW3	34	CLK
11	NC	35	$\overline{\text{LE}}$
12	SW2	36	CLR
13	NC	37	D <sub>OUT</sub>
14	SW2	38	NC
15	NC	39	SW7
16	SW1	40	NC
17	NC	41	SW7
18	SW1	42	NC
19	NC	43	SW6
20	SW0	44	NC
21	NC	45	SW6
22	SW0	46	NC
23	NC	47	SW5
24	V <sub>PP</sub>	48	NC

**28-Lead PLCC  
Package Outline (PJ)**



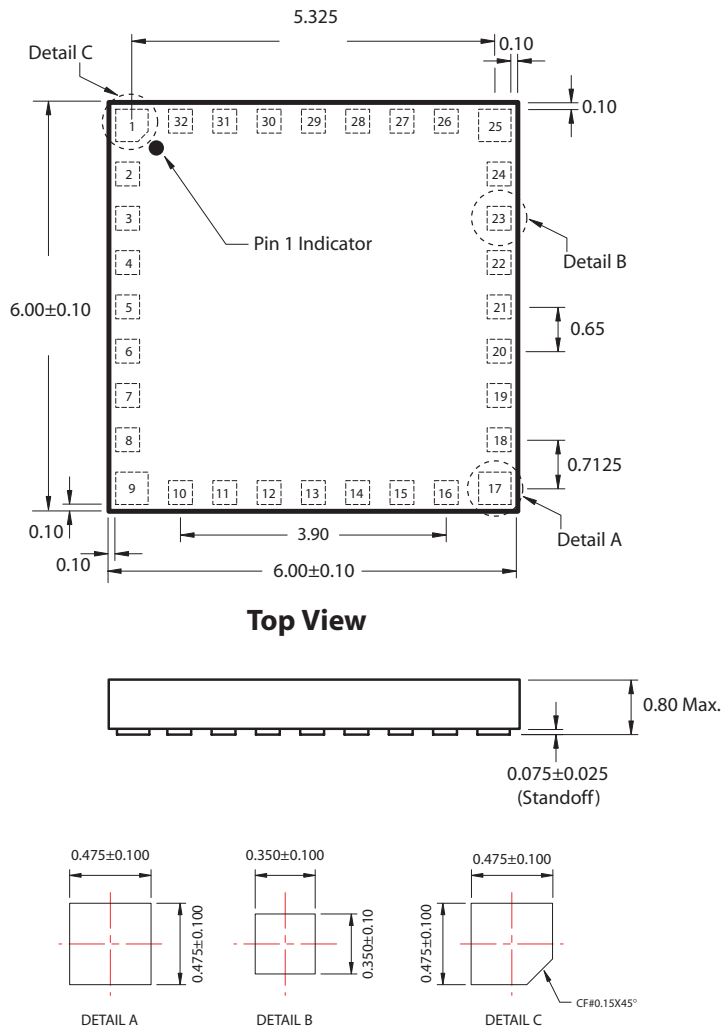
**Pin Configuration**

Pin #	Pin Name	Pin #	Pin Name
1	SW3	15	NC
2	SW3	16	D <sub>IN</sub>
3	SW2	17	CLK
4	SW2	18	$\overline{\text{LE}}$
5	SW1	19	CLR
6	SW1	20	D <sub>OUT</sub>
7	SW0	21	SW7
8	SW0	22	SW7
9	NC	23	SW6
10	V <sub>PP</sub>	24	SW6
11	NC	25	SW5
12	V <sub>NN</sub>	26	SW5
13	GND	27	SW4
14	V <sub>DD</sub>	28	SW4



**32-Lead BCC  
Package Outline (B1)**

**Pin Configuration**



Pin #	Pin Name	Pin #	Pin Name
1	NC	17	NC
2	SW5	18	V <sub>NN</sub>
3	SW5	19	NC
4	SW4	20	GND
5	SW4	21	V <sub>DD</sub>
6	SW3	22	D <sub>IN</sub>
7	SW3	23	CLK
8	SW2	24	$\overline{LE}$
9	SW2	25	CLR
10	NC	26	D <sub>OUT</sub>
11	SW1	27	NC
12	SW1	28	SW7
13	SW0	29	SW7
14	SW0	30	SW6
15	NC	31	SW6
16	V <sub>PP</sub>	32	NC

Note: All dimensions are in mm and angles are in degrees

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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